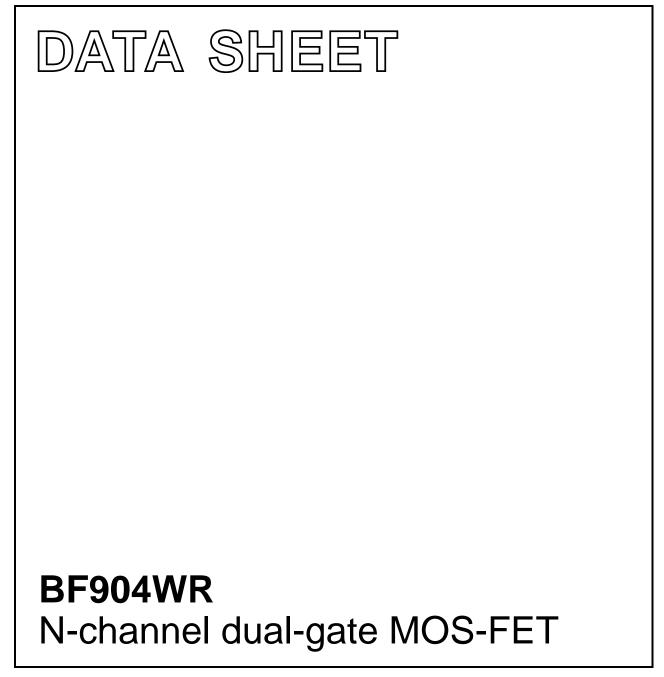
DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 1995 Apr 25 2010 Sep 15



BF904WR

N-channel dual-gate MOS-FET

FEATURES

- Specially designed for use at 5 V supply voltage
- Short channel transistor with high forward transfer admittance to input capacitance ratio
- · Low noise gain controlled amplifier up to 1 GHz
- Superior cross-modulation performance during AGC.

APPLICATIONS

• VHF and UHF applications with 3 to 7 V supply voltage such as television tuners and professional communications equipment.

DESCRIPTION

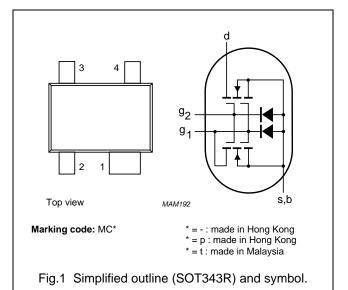
Enhancement type field-effect transistor in a plastic microminiature SOT343R package. The transistor consists of an amplifier MOS-FET with source and substrate interconnected and an internal bias circuit to ensure good cross-modulation performance during AGC.

CAUTION

The device is supplied in an antistatic package. The gate-source input must be protected against static discharge during transport or handling.

PINNING

| PIN | SYMBOL | DESCRIPTION |
|-----|------------|-------------|
| 1 | s, b | source |
| 2 | d | drain |
| 3 | g 2 | gate 2 |
| 4 | 9 1 | gate 1 |



QUICK REFERENCE DATA

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|--------------------|--------------------------------|-------------|------|------|------|------|
| V _{DS} | drain-source voltage | | - | - | 7 | V |
| I _D | drain current | | - | - | 30 | mA |
| P _{tot} | total power dissipation | | - | - | 280 | mW |
| Tj | operating junction temperature | | - | - | 150 | °C |
| y _{fs} | forward transfer admittance | | 22 | 25 | 30 | mS |
| C _{ig1-s} | input capacitance at gate 1 | | - | 2.2 | 2.6 | pF |
| C _{rs} | reverse transfer capacitance | f = 1 MHz | - | 25 | 35 | fF |
| F | noise figure | f = 800 MHz | - | 2 | - | dB |

BF904WR

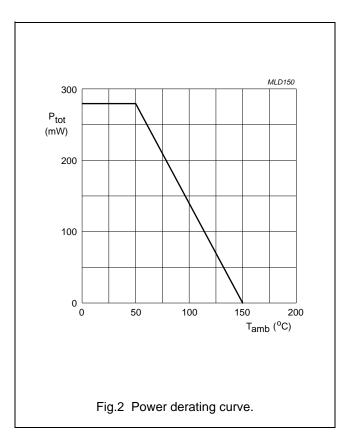
LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------|--------------------------------|--|------|------|------|
| V _{DS} | drain-source voltage | | - | 7 | V |
| I _D | drain current | | - | 30 | mA |
| I _{G1} | gate 1 current | | - | ±10 | mA |
| I _{G2} | gate 2 current | | - | ±10 | mA |
| P _{tot} | total power dissipation | up to T _{amb} = 50 °C; see Fig.2; note 1 | - | 280 | mW |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Τ _j | operating junction temperature | | - | +150 | °C |

Note

1. Device mounted on a printed-circuit board.



BF904WR

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|---------------------|---|--------------------------------|-------|------|
| R _{th j-a} | thermal resistance from junction to ambient | note 1 | 350 | K/W |
| R _{th j-s} | thermal resistance from junction to soldering point | T _s = 91 °C; note 2 | 210 | K/W |

Notes

- 1. Device mounted on a printed-circuit board.
- 2. T_s is the temperature at the soldering point of the source lead.

STATIC CHARACTERISTICS

 $T_j = 25 \ ^{\circ}C$; unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------------|---------------------------------|---|------|------|------|
| V _{(BR)G1-SS} | gate 1-source breakdown voltage | $V_{G2-S} = V_{DS} = 0; I_{G1-S} = 10 \text{ mA}$ | 6 | 15 | V |
| V _{(BR)G2-SS} | gate 2-source breakdown voltage | $V_{G1-S} = V_{DS} = 0; I_{G2-S} = 10 \text{ mA}$ | 6 | 15 | V |
| V _{(F)S-G1} | forward source-gate 1 voltage | $V_{G2-S} = V_{DS} = 0; I_{S-G1} = 10 \text{ mA}$ | 0.5 | 1.5 | V |
| V _{(F)S-G2} | forward source-gate 2 voltage | $V_{G1-S} = V_{DS} = 0; I_{S-G2} = 10 \text{ mA}$ | 0.5 | 1.5 | V |
| V _{G1-S(th)} | gate 1-source threshold voltage | $V_{G2-S} = 4V; V_{DS} = 5V; I_D = 20 \ \mu A$ | 0.3 | 1 | V |
| V _{G2-S(th)} | gate 2-source threshold voltage | $V_{G1-S} = V_{DS} = 5 \text{ V}; \text{ I}_{D} = 20 \mu\text{A}$ | 0.3 | 1.2 | V |
| I _{DSX} | drain-source current | V_{G2-S} = 4 V; V_{DS} = 5 V; R_{G1} = 120 k Ω ; note 1 | 8 | 13 | mA |
| I _{G1-SS} | gate 1 cut-off current | $V_{G2-S} = V_{DS} = 0; V_{G1-S} = 5 V$ | - | 50 | nA |
| I _{G2-SS} | gate 2 cut-off current | $V_{G1-S} = V_{DS} = 0; V_{G2-S} = 5 V$ | - | 50 | nA |

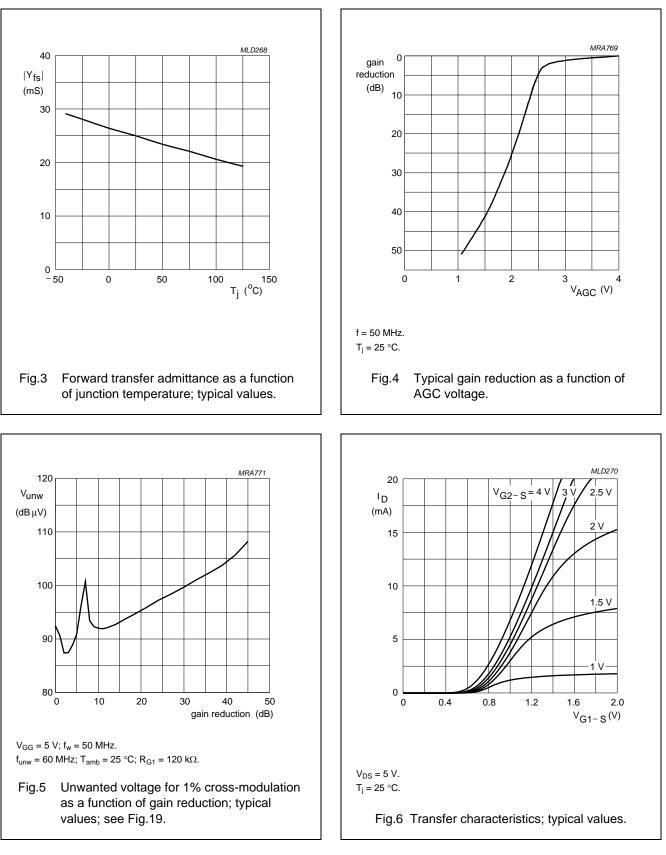
Note

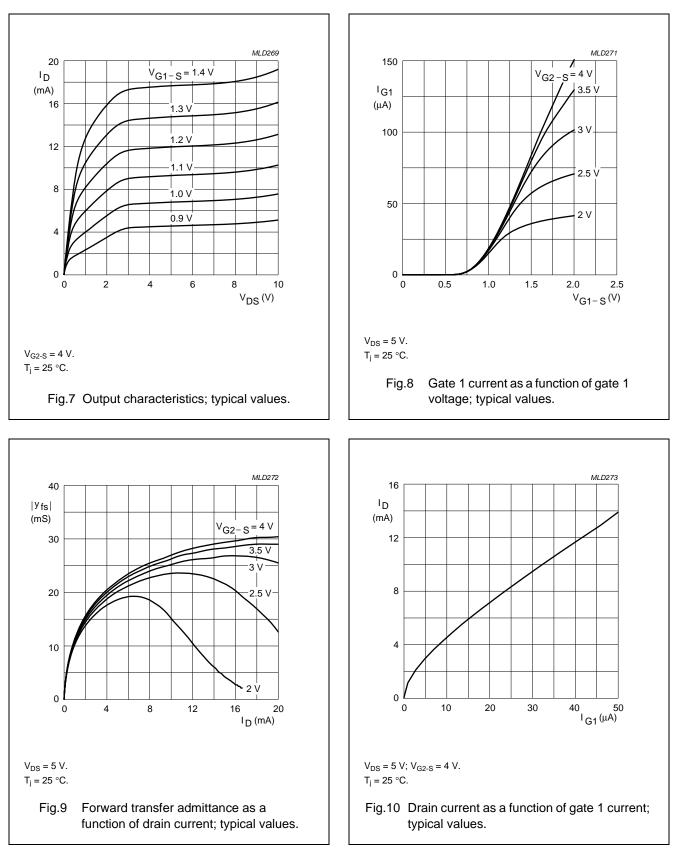
1. R_G connects gate 1 to $V_{GG} = 5$ V.

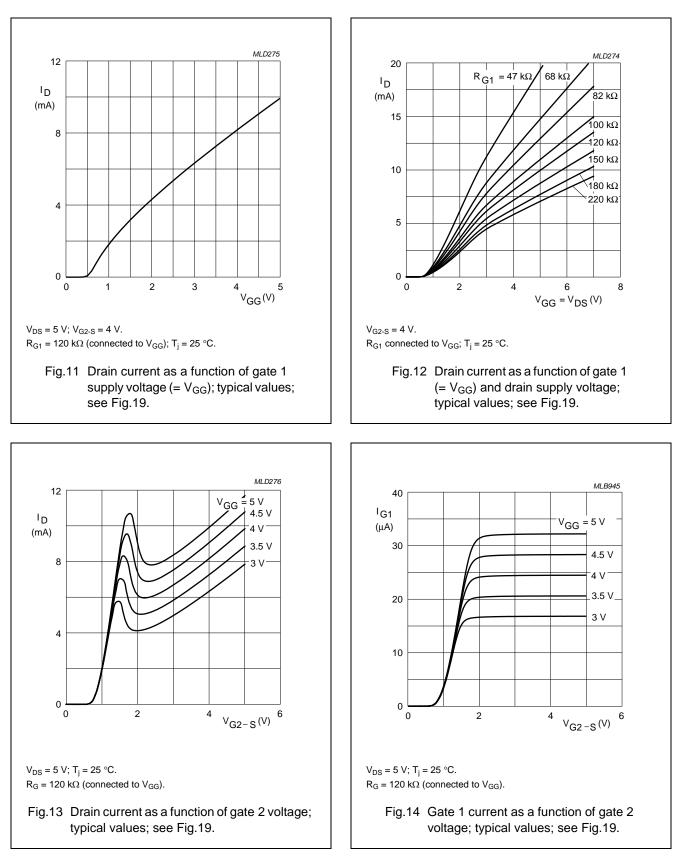
DYNAMIC CHARACTERISTICS

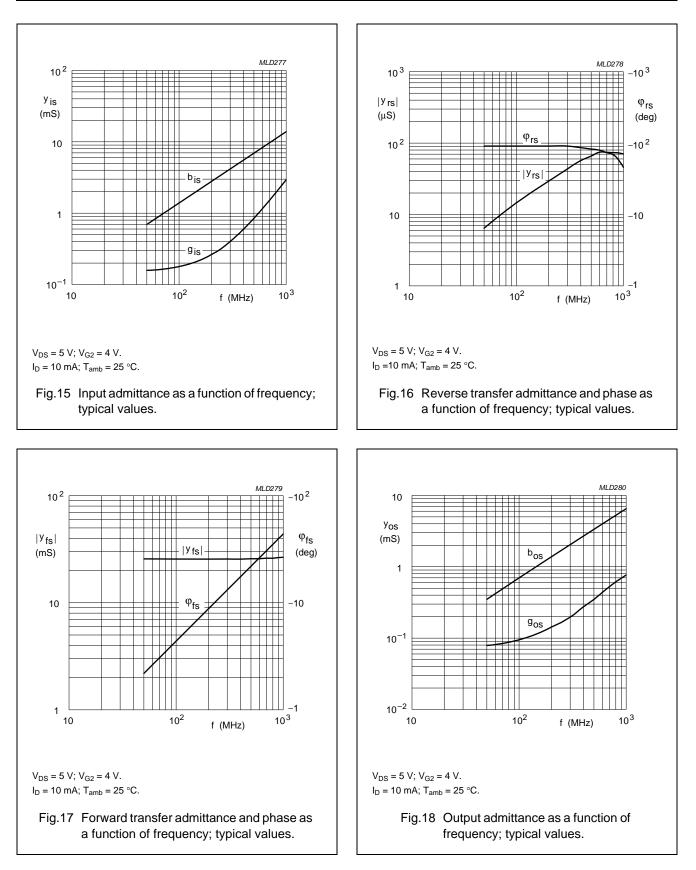
Common source; T_{amb} = 25 °C; V_{DS} = 5 V; V_{G2-S} = 4 V; I_D = 10 mA; unless otherwise specified.

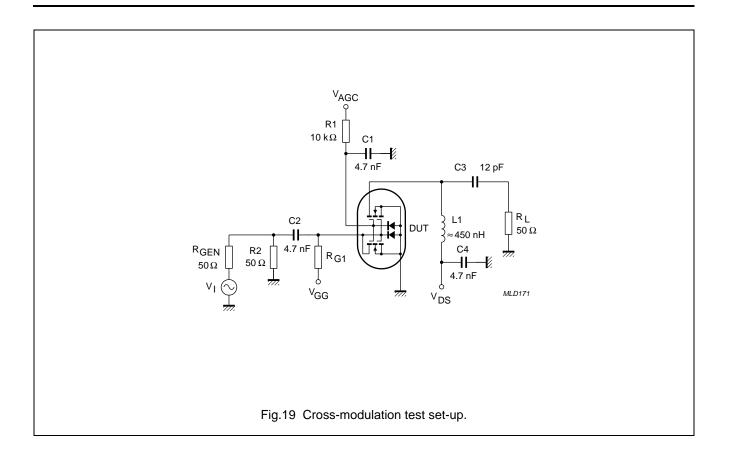
| SYMBOL | PARAMETER | IETER CONDITIONS | | TYP. | MAX. | UNIT |
|--------------------|------------------------------|---|----|------|------|------|
| y _{fs} | forward transfer admittance | pulsed; T _j = 25 °C | 22 | 25 | 30 | mS |
| C _{ig1-s} | input capacitance at gate 1 | f = 1 MHz | - | 2.2 | 2.6 | pF |
| C _{ig2-s} | input capacitance at gate 2 | f = 1 MHz | 1 | 1.5 | 2 | pF |
| C _{os} | drain-source capacitance | f = 1 MHz | 1 | 1.3 | 1.6 | pF |
| C _{rs} | reverse transfer capacitance | f = 1 MHz | - | 25 | 35 | fF |
| F | noise figure | $f = 200 \text{ MHz}; G_S = 2 \text{ mS}; B_S = B_{Sopt}$ | _ | 1 | 1.5 | dB |
| | | $f = 800 \text{ MHz}; G_S = G_{Sopt}; B_S = B_{Sopt}$ | - | 2 | 2.8 | dB |











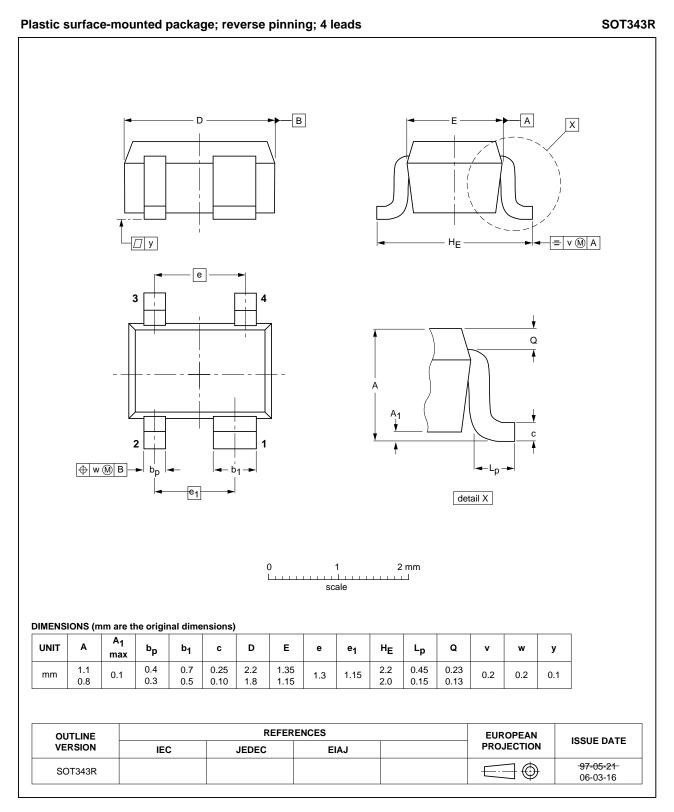
| | e i Scattening parameters. $v_{DS} = 3 v$, $v_{G2-S} = 4 v$, $v_{D} = 10 mA$ | | | | | | | |
|------------|---|---------------------------------|----------------------|-----------------|----------------------|-----------------|----------------------|----------------|
| f | s ₁₁ | s ₁₁ s ₂₁ | | s ₁₂ | | s ₂₂ | - | |
| ' (MHz) | MAGNITUDE (ratio) | ANGLE (deg) | MAGNITUDE (ratio) | ANGLE (deg) | MAGNITUDE (ratio) | ANGLE (deg) | MAGNITUDE (ratio) | ANGLE (deg) |
| 40 | 0.989 | -3.4 | 2.420 | 175.7 | 0.000 | 79.9 | 0.993 | -1.6 |
| 100 | 0.985 | -8.3 | 2.414 | 169.1 | 0.001 | 78.3 | 0.992 | -3.9 |
| 200 | 0.976 | -16.4 | 2.368 | 158.8 | 0.003 | 80.3 | 0.987 | -7.8 |
| 300 | 0.958 | -24.1 | 2.301 | 148.5 | 0.004 | 73.7 | 0.980 | -11.4 |
| 400 | 0.942 | -32.0 | 2.251 | 138.8 | 0.005 | 70.7 | 0.974 | -15.2 |
| 500 | 0.918 | -39.3 | 2.170 | 129.5 | 0.005 | 67.2 | 0.966 | -18.7 |
| 600 | 0.899 | -46.0 | 2.080 | 120.7 | 0.005 | 67.8 | 0.958 | -22.2 |
| 700 | 0.876 | -52.6 | 2.001 | 112.1 | 0.005 | 68.6 | 0.951 | -25.5 |
| 800 | 0.852 | -58.8 | 1.924 | 103.2 | 0.005 | 72.9 | 0.944 | -28.9 |
| 900 | 0.823 | -64.9 | 1.829 | 94.7 | 0.005 | 78.7 | 0.937 | -32.1 |
| 1000 | 0.800 | -70.9 | 1.747 | 86.5 | 0.005 | 88.3 | 0.933 | -35.2 |
| 1200 | 0.750 | -82.4 | 1.621 | 70.7 | 0.005 | 120.5 | 0.928 | -41.7 |
| 1400 | 0.719 | -92.7 | 1.535 | 54.6 | 0.008 | 139.8 | 0.930 | -48.4 |
| 1600 | 0.682 | -102.5 | 1.424 | 39.4 | 0.010 | 137.8 | 0.924 | -54.9 |
| 1800 | 0.642 | -109.8 | 1.349 | 22.5 | 0.013 | 156.8 | 0.928 | -62.9 |
| 2000 | 0.602 | -116.5 | 1.283 | 1.1 | 0.018 | 175.1 | 0.928 | -73.1 |
| 2200 | 0.547 | -124.9 | 1.130 | -15.1 | 0.014 | 172.6 | 0.887 | -81.0 |
| 2400 | 0.596 | -128.7 | 1.018 | -49.1 | 0.040 | -163.9 | 0.837 | -95.8 |
| 2600 | 0.682 | -132.6 | 0.979 | -79.4 | 0.077 | -164.0 | 0.778 | -109.6 |
| 2800 | 0.771 | -142.5 | 0.804 | -116.2 | 0.120 | 178.8 | 0.629 | -119.5 |
| 3000 | 0.793 | -157.5 | 0.541 | -153.5 | 0.149 | 158.3 | 0.479 | -119.9 |

Table 1 Scattering parameters: V_{DS} =5 V; V_{G2-S} = 4 V; I_D = 10 mA

Table 2 Noise data: V_{DS} = 5 V; V_{G2-S} = 4 V; I_D = 10 mA

| f | F _{min} | Г | opt | r |
|-------|------------------|---------|-------|-------|
| (MHz) | (dB) | (ratio) | (deg) | 'n |
| 800 | 2.00 | .686 | 49.6 | 50.40 |

PACKAGE OUTLINE



BF904WR

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| DOCUMENT STATUS ⁽¹⁾ | PRODUCT STATUS ⁽²⁾ | DEFINITION |
|-----------------------------------|----------------------------------|---|
| Objective data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary data sheet | Qualification | This document contains data from the preliminary specification. |
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